ΡΛΝ	JIT
	SEMI
	CONDUCTOR

30V N-Channel Enhancement Mode MOSFET

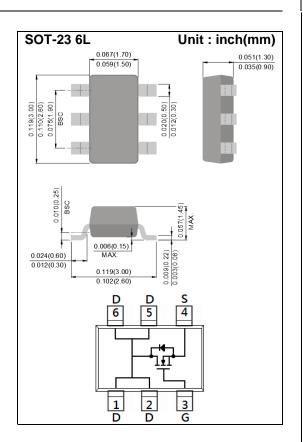


Features

- RDS(ON) , VGS@10V, ID@6.8A<32mΩ
- RDS(ON) , VGS@4.5V,ID@4.3A<47mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc..
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S04



Maximum Ratings and Thermal Characteristics (TA=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage	V _{GS}	<u>+</u> 20	V	
Continuous Drain Current		I _D	6.8	А
Pulsed Drain Current		I _{DM}	27.2	А
Power Dissipation	T _a =25°C	PD	2	W
	Derate above 25°C		16	mW/ºC
Operating Junction and Storage Te	TJ,TSTG	-55~150	٥C	
Typical Thermal Resistance - Junction to Ambient ^(Note 3)		R _{θJA}	62.5	°C/W



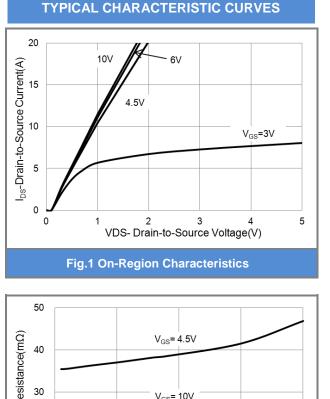
Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.4	2.1	V
		V _{GS} =10V, I _D =6.8A	-	26	32	mΩ
Drain-Source On-State Resistance	$R_{DS(on)}$	ⁿ⁾ V _{GS} =4.5V, I _D =4.3A	-	38	47	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V	-	0.01	1	uA
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Qg		-	7.8	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V, I _D =6.8A, V _{GS} =10V ^(Note 1,2)	-	1.2	-	
Gate-Drain Charge	Q_{gd}		-	1.5	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V,	-	343	-	pF
Output Capacitance	Coss		-	48	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	34	-	
Switching						
Turn-On Delay Time	td _(on)		-	3.1	-	
Turn-On Rise Time	tr	V _{DD} =15V, I _D =6.8A, V _{GS} =10V,		40	-	
Turn-Off Delay Time	td _(off)			38	-	ns
Turn-Off Fall Time	tf	$R_G=6\Omega^{(Note 1,2)}$	-	39	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					2.0	Δ
Diode Forward Current	ls		-	-	2.0	A
Diode Forward Voltage	V _{SD}	Is=1.0A, V _{GS} =0V	-	0.75	1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





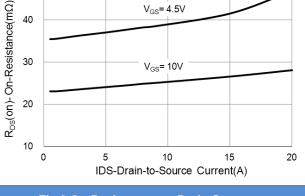
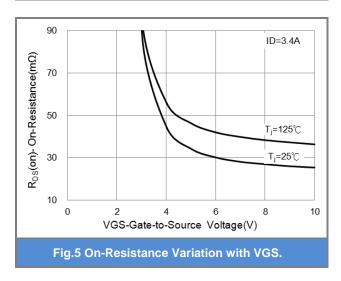


Fig.3 On-Resistance vs. Drain Current



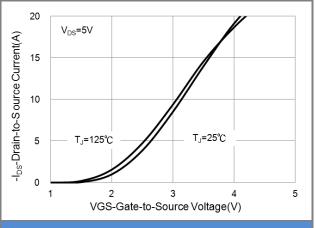


Fig.2 Transfer Characteristics

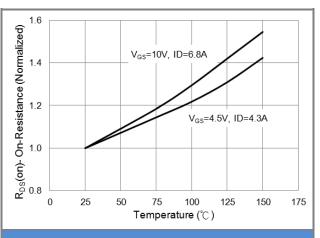
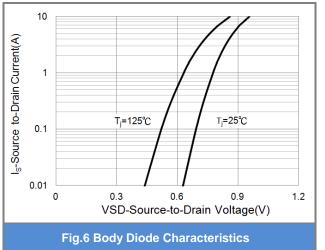


Fig.4 On-Resistance vs. Junction temperature





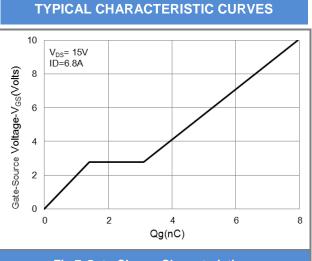


Fig.7 Gate-Charge Characteristics

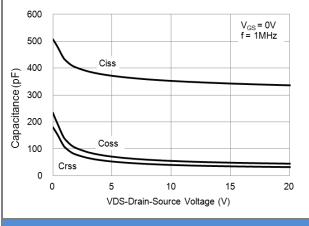


Fig.9 Capacitance vs. Drain-Source Voltage.

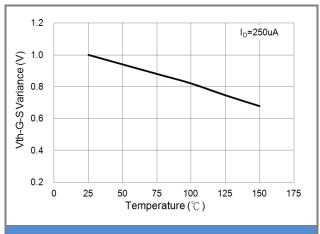


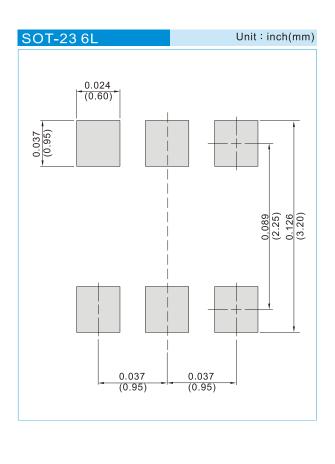
Fig.8 Threshold Voltage Variation with Temperature.



PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6404_S1_00001	SOT-23 6L	3K pcs / 7" reel	S04	Halogen free RoHS compliant

MOUNTING PAD LAYOUT







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